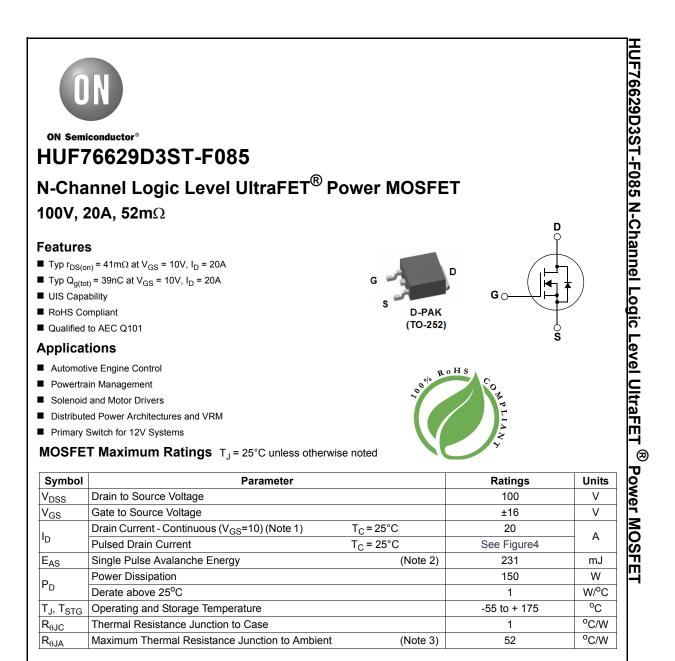
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# Onsemi

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# Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
HUF76629D3ST	HUF76629D3ST-F085	D-PAK(TO-252)	13"	12mm	2500 units

Notes:

1: Current is limited by bondwire configuration.

2: Starting T<sub>J</sub> = 25°C, L = 1.8mH, I<sub>AS</sub> = 16A, V<sub>DD</sub> = 100V during inductor charging and V<sub>DD</sub> = 0V during time in avalanche 3:  $R_{\theta,JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>0JC</sub> is guaranteed by design while R<sub>0JA</sub> is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units
Off Cha	aracteristics					
B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V	100	-	-	V
	Drain to Source Leakage Current	$V_{DS} = 100V, T_{J} = 25^{\circ}C$ $V_{GS} = 0V T_{J} = 175^{\circ}C(Note 4)$	-	-	1	μA mA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = 00$ $T_{J} = 175$ C(Note 4) $V_{GS} = \pm 16V$	-	-	±100	nA
	aracteristics			1	1	Γ
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	1.0	1.6	3.0	V
		$I_{\rm D} = 20$ A, $T_{\rm J} = 25^{\rm o}$ C	-	41	52	mΩ
(DS(op)	Drain to Source On Resistance	$V_{GS}$ = 10V $T_{J}$ = 175°C(Note 4)	-	102	128	mΩ
V <sub>GS(th)</sub> <sup>r</sup> DS(on) <b>Dynami</b> C <sub>iss</sub> C <sub>oss</sub> C <sub>rss</sub> R <sub>g</sub> Q <sub>g(ToT)</sub>		$I_D = 20A,$ $T_J = 25^{\circ}C$ $V_{GS} = 4.5V$ $T_J = 175^{\circ}C(Note 4)$		47 115	55 135	mΩ mΩ
Junam	ic Characteristics					
•		T		1000		
	Input Capacitance	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V,	-	1280	-	pF
C <sub>oss</sub>	Output Capacitance	f = 1MHz	-	214 33	-	рF
	Reverse Transfer Capacitance Gate Resistance	f = 1MHz	-	2.5	-	pF Ω
5	Total Gate Charge		-	2.5	- 43	nC
	Threshold Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 50V$ $V_{GS} = 0 \text{ to } 2V$ $I_D = 20A$	-	2.3	43	nC
Q <sub>g(th)</sub>	Gate to Source Gate Charge	$V_{GS} = 0$ to 2V $I_D = 20A$	-	3.5	3	nC
Q <sub>gs</sub>	Gate to Drain "Miller" Charge		-	3.5 11	-	nC
Q <sub>gd</sub>	Gale to Dialiti Miller Charge		-	11	-	пс
Swita	hing Characteristics					
Switc	hing Characteristics			T	27	1

t <sub>on</sub>	Turn-On Time		-	-	27	ns
t <sub>d(on)</sub>	Turn-On Delay Time		-	7	-	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 50V, I <sub>D</sub> = 20A, V <sub>GS</sub> = 10V, R <sub>GEN</sub> = 8.2Ω	-	12	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>GS</sub> = 10V, R <sub>GEN</sub> = 8.2Ω	-	38	-	ns
t <sub>f</sub>	Fall Time		-	5	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	47	ns

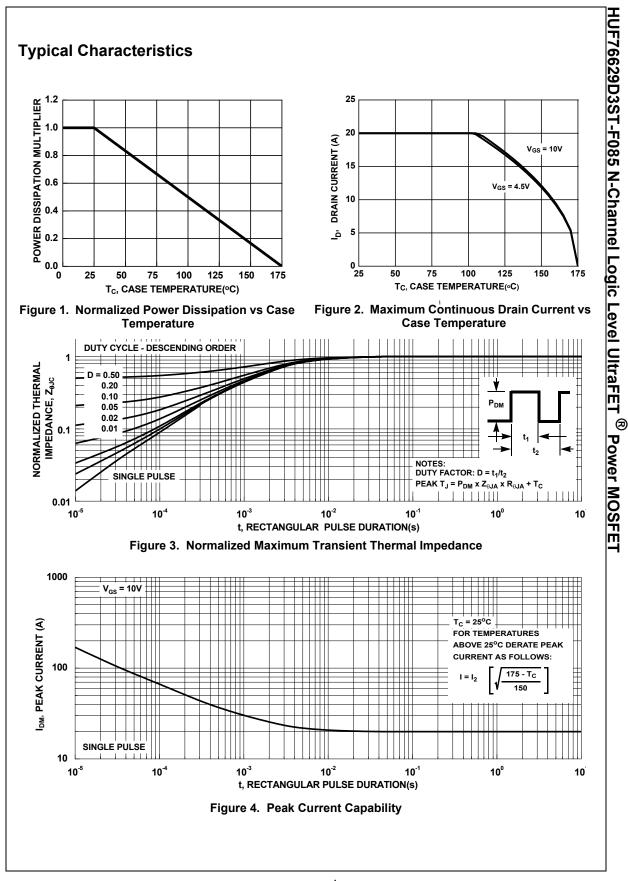
# **Drain-Source Diode Characteristics**

V	Source to Drain Diode Voltage	I <sub>SD</sub> = 20A, V <sub>GS</sub> = 0V	-	-	1.25	V
V <sub>SD</sub>	Source to Drain Diode Voltage	I <sub>SD</sub> = 10A, V <sub>GS</sub> = 0V	-	-	1.0	V
T <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 20A, dI <sub>SD</sub> /dt = 100A/μs,	-	77	99	ns
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DD</sub> =80V	-	221	305	nC

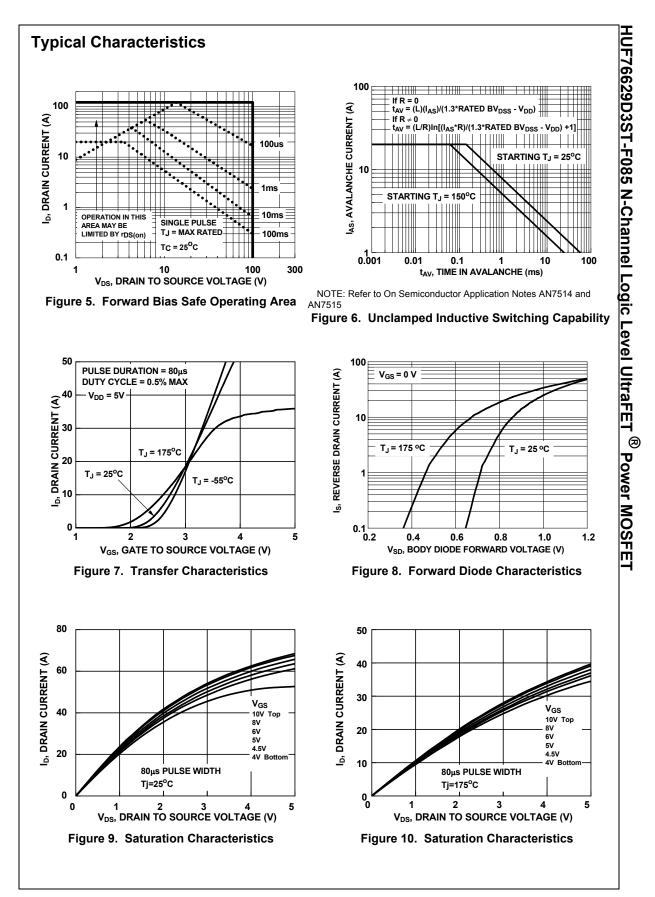
## Notes:

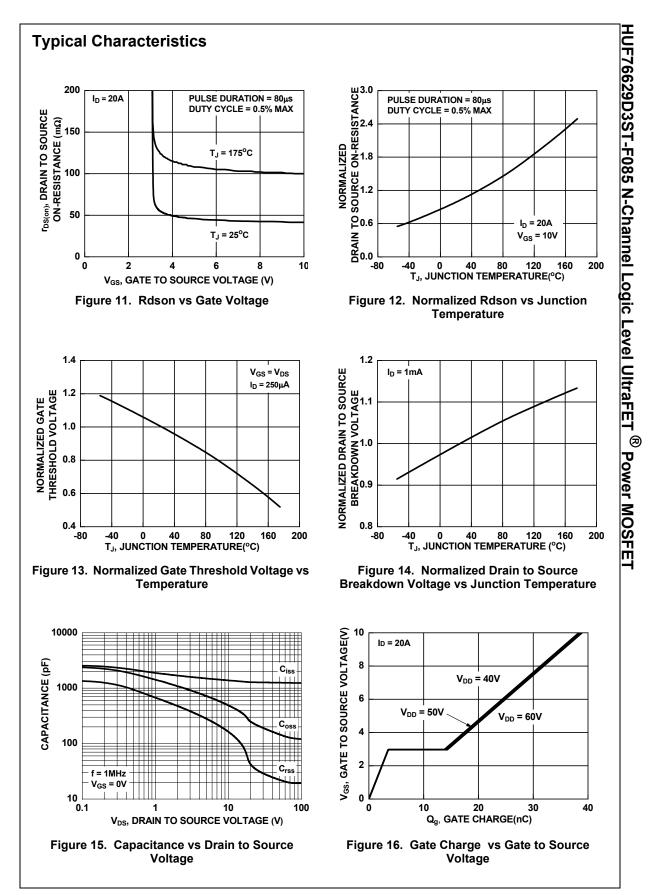
4: The maximum value is specified by design at  $T_J$  = 175°C. Product is not tested to this condition in production.





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